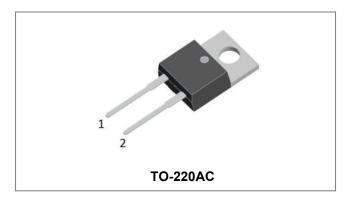


## MUR1060

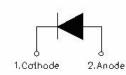
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# **MUR1060 ULTRAFAST RECTIFIER**



# Circuit Diagram



# Features

- Ultra-Fast Switching
  High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Applications

- Switching Power Supply
- Power Switching Circuits
  - General Purpose

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	600	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>c</sub> =100°C, rectangular wave form	10	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	125	A

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 10A, Pulse, T <sub>J</sub> = 25°C	1.25	2.2	V
	V <sub>F2</sub>	@ 10A, Pulse, T <sub>J</sub> = 100°C	-	2.0	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25°C	0.03	5	μA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 100°C	-	50	μA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	41	50	ns

\* Pulse width < 300 µs, duty cycle < 2%

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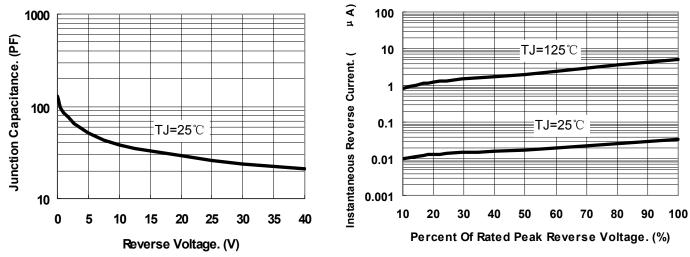
# MUR1060

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## **Thermal-Mechanical Specifications:**

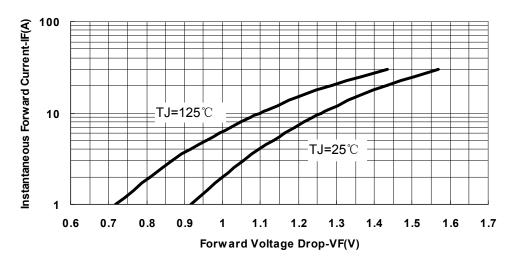
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ hetaJc}}$	DC operation	4	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	TO-220AC			











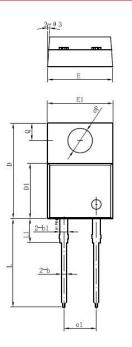


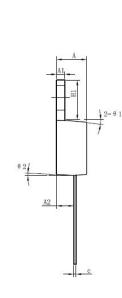
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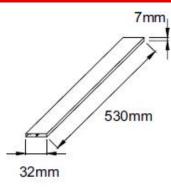
## **Mechanical Dimensions TO-220AC**





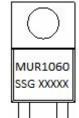
#### **Dimensions in millimeters** Symbol Min. Typical Max. 4.47 4.85 Α 4.70 A1 1.17 1.27 1.37 A2 2.52 2.69 2.89 0.81 0.96 b 0.71 b1 1.17 1.27 1.37 С 0.31 0.38 0.61 D 14.64 14.94 15.24 D1 8.50 8.07 8.90 10.16 Е 10.01 10.31 E1 9.98 10.18 10.38 4.98 e1 5.08 5.18 H1 6.04 6.24 6.44 L 13.00 13.86 14.08 L1 3.56 3.80 3.96 ΦP 3.74 3.84 4.04 Q 2.54 2.74 2.94 Θ1 5° Θ2 4°

## **Tube Specification**



# Marking Diagram

Θ3



#### Where XXXXX is YYWWL

MUR = Device Type 10 = Forward Curre

= Forward Current (10A) = Reverse Voltage(600V)

4°

= SSG

60 SSG

YY WW

L

- = Year
  - = Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

## **Ordering Information**

Device	Package	Shipping	
MUR1060	TO-220AC (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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## MUR1060





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